

# DCR2360C24

# **Phase Control Thyristor**

DS6039-2 June 2019 (LN38858)

# FEATURES

- Double Side Cooling
- High Surge Capability

### **KEY PARAMETERS**

V <sub>DRM</sub>	2400 V
I <sub>T(AV)</sub>	2360 A
I <sub>TSM</sub>	35000 A
dV/dt*	1000 V/µs
dl/dt	200 A/µs

#### \* Higher dV/dt selections available

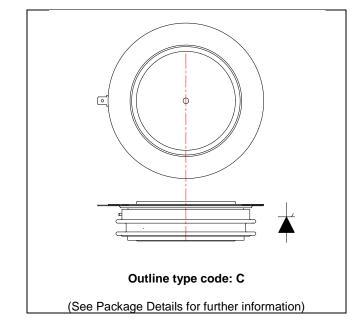


Fig. 1 Package outline

### **APPLICATIONS**

- High Power Drives
- High Voltage Power Supplies
- Static Switches

### **VOLTAGE RATINGS**

Part and Ordering Number	Repetitive Peak Voltages V <sub>DRM</sub> and V <sub>RRM</sub> V	Conditions
DCR2360C24 DCR2360C22 DCR2360C20	2400 2200 2000	$\begin{array}{l} T_{vj} = -40^{\circ}\text{C to } 125^{\circ}\text{C}, \\ I_{DRM} = I_{RRM} = 250\text{mA}, \\ V_{DRM}, V_{RRM}  t_p = 10\text{ms}, \\ V_{DSM} \& V_{RSM} = \\ V_{DRM} \& V_{RRM}  +100V \\ respectively \end{array}$

Lower voltage grades available.

### **ORDERING INFORMATION**

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

#### DCR2360C24

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.



## **CURRENT RATINGS**

T<sub>case</sub> = 60°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Si	de Cooled			
I <sub>T(AV)</sub>	Mean on-state current	Half wave resistive load	2360	А
I <sub>T(RMS)</sub>	RMS value	-	3710	А
Ι <sub>Τ</sub>	Continuous (direct) on-state current	-	3340	А

# SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I <sub>TSM</sub>	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 125^{\circ}C$	35.0	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$V_R = 0$	6.13	MA <sup>2</sup> s

# THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions	5	Min.	Max.	Units
R <sub>th(j-c)</sub>	Thermal resistance – junction to case	Double side cooled	DC	-	0.0125	°C/W
R <sub>th(c-h)</sub>	Thermal resistance – case to heatsink	Double side cooled	DC	-	0.004	°C/W
T <sub>vj</sub>	Virtual junction temperature	Blocking V <sub>DRM</sub> / <sub>VRRM</sub>		-	125	°C
T <sub>stg</sub>	Storage temperature range			-40	140	°C
Fm	Clamping force			40	50	kN

# DYNAMIC CHARACTERISTICS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
I <sub>RRM</sub> /I <sub>DRM</sub>	Peak reverse and off-state current	At V <sub>RRM</sub> /V <sub>DRM</sub> , T <sub>case</sub> = 125°C		-	250	mA
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V <sub>DRM</sub> , T <sub>j</sub> = 125°C, ga	ate open	1000	-	V/µs
dl/dt	Rate of rise of on-state current	From 67% V <sub>DRM</sub> to 3000A	Repetitive 50Hz	-	200	A/µs
		Gate source 30V, $10\Omega$ ,	Non-repetitive	-	1000	A/µs
		$t_r < 0.5 \mu s, T_j = 125^{\circ}C$				
VT	On-state voltage	I <sub>T</sub> = 3000A, T <sub>case</sub> = 125°C			1.50	V
$V_{T(TO)}$	Threshold voltage	T <sub>case</sub> = 125°C		-	0.96	V
r <sub>T</sub>	On-state slope resistance	T <sub>case</sub> = 125°C		-	0.179	mΩ
t <sub>gd</sub>	Delay time	$V_D = 67\% V_{DRM}$ , gate source	30V, 10Ω	-	3.0	μs
		$t_r=0.5\mu s, T_j=25^\circ C$				
tq	Turn-off time	$T_j = 125^{\circ}C, V_R = 100V, dl/dt$	= 10A/µs,	-	400	μs
		$dV_{DR}/dt = 20V/\mu s$ linear to 67	7% V <sub>drm</sub>			
Qs	Stored charge	$I_T = 4000A$ , tp = 1000us, $T_j$ =	I <sub>T</sub> = 4000A, tp = 1000us,T <sub>i</sub> = 125°C,		3600	μC
I <sub>RR</sub>	Reverse recovery current	dl/dt =10A/µs,		-	175	А
١L	Latching current	$T_j = 25^{\circ}C,$		-	1	А
I <sub>H</sub>	Holding current	$T_j = 25^{\circ}C,$		-	200	mA

# GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
V <sub>GT</sub>	Gate trigger voltage	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	3	V
$V_{\text{GD}}$	Gate non-trigger voltage	At 40% V <sub>DRM</sub> , T <sub>case</sub> = 125°C	0.3	V
I <sub>GT</sub>	Gate trigger current	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	300	mA
I <sub>GD</sub>	Gate non-trigger current	At 40% V <sub>DRM,</sub> T <sub>case</sub> = 125°C	20	mA

# **G BYNEX**

# CURVES

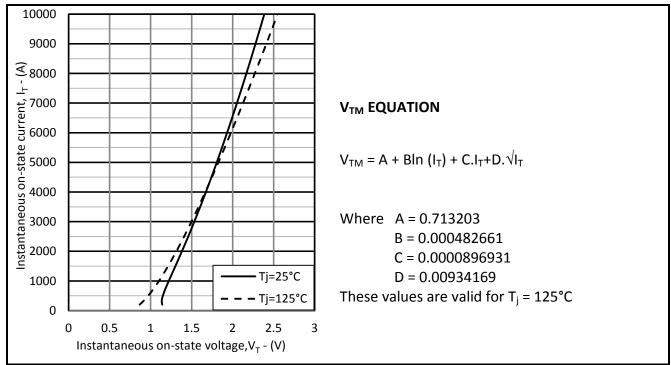


Fig.2 Maximum & minimum on-state characteristics

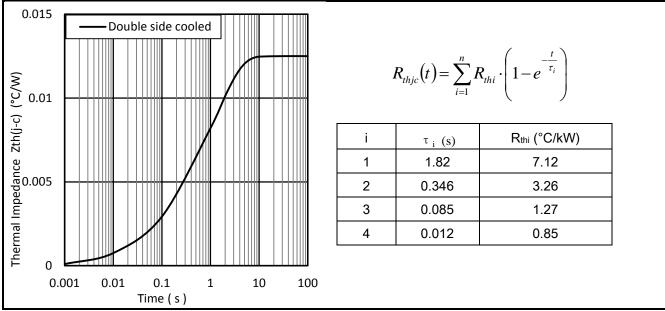
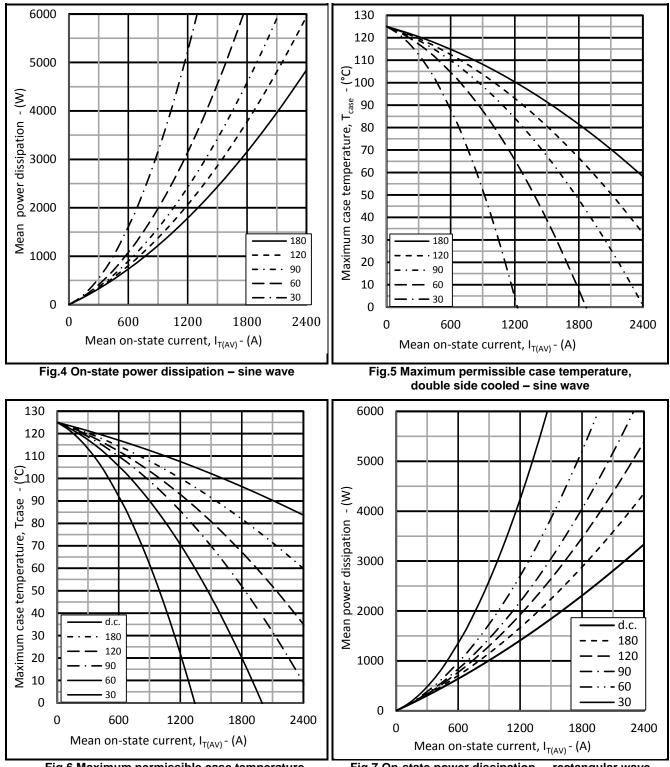
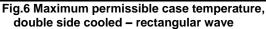


Fig.3 Maximum (limit) transient thermal impedance - junction to case (°C/W)











## DCR2360C24

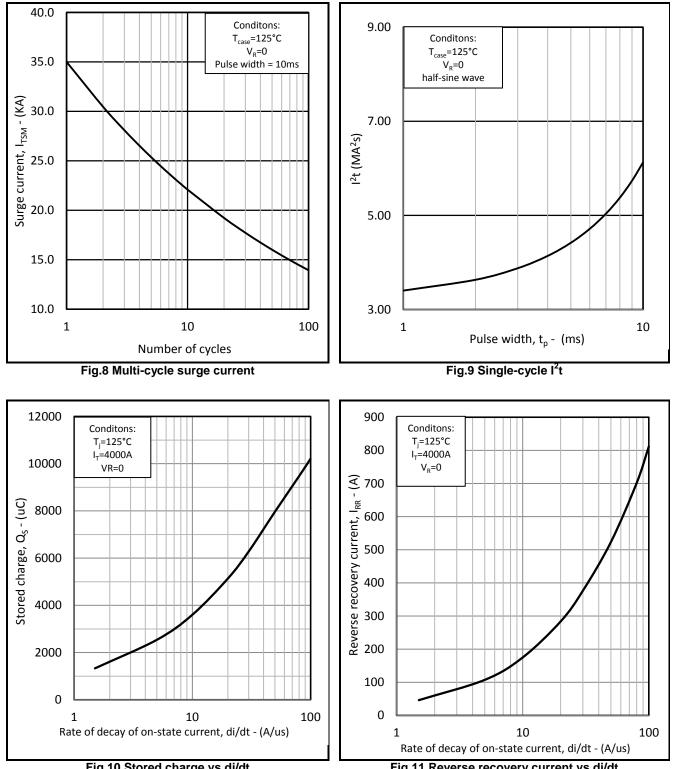


Fig.10 Stored charge vs di/dt

Fig.11 Reverse recovery current vs di/dt

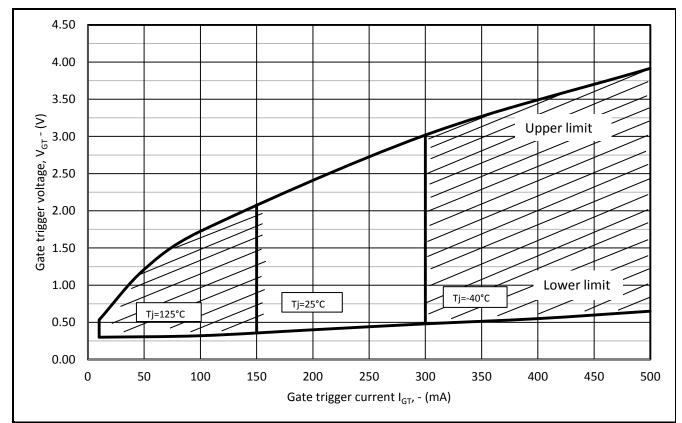


Fig.12 Gate characteristics

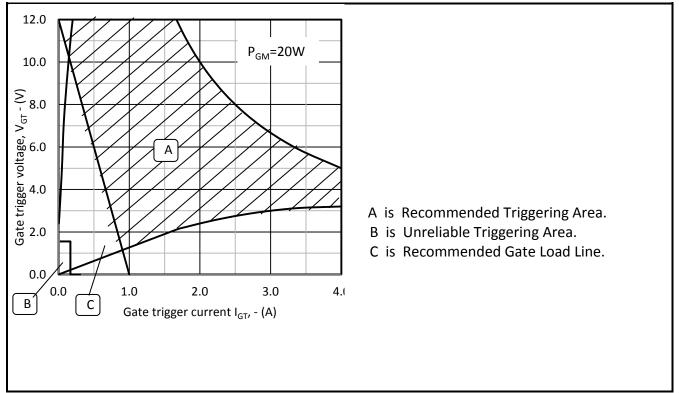


Fig.13 Gate characteristics

@ BYNEX



## PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.

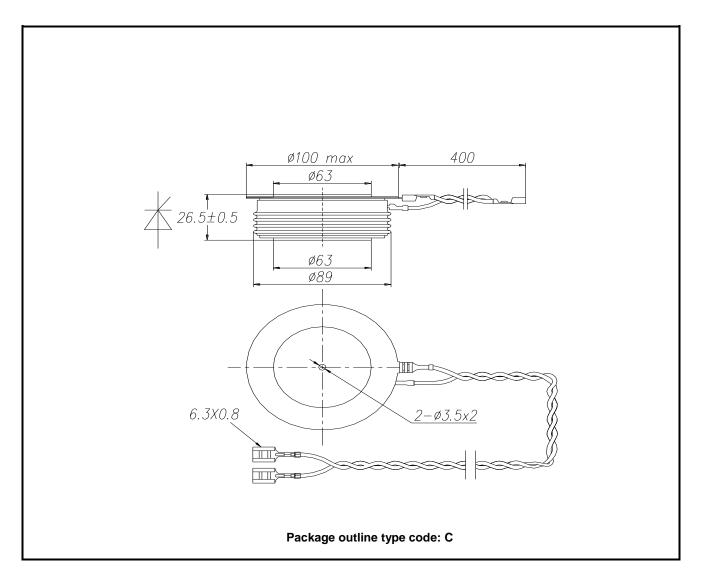


Fig.14 Package outline



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